

DD200 ADD200 KDD200

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _C =100°C	150			200	A
I _{F(RMS)}	RMS forward current	Single side cooled, T _C =100°C	150			314	A
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RSM} = V _{DRM} &V _{RRM} +200V	150	600		1800	V
I _{RRM}	Repetitive peak current	at V _{RRM}	150			12	mA
I _{FSM}	Surge forward current	10ms half sine wave	150			8.00	KA
I ² t	I ² T for fusing coordination	V _R =0.6V _{RRM}				326	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.75	V
r _F	Forward slop resistance					0.88	mΩ
V _{FM}	Peak forward voltage	I _{FM} =600A	25			1.38	V
R _{th(j-c)}	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.210	°C /W
V _{iso}	Isolation voltage	50Hz, R.M.S, t=1 min, I _{iso} : 1mA(max)		2500			V
F _m	Terminal connection torque(M5)					3.0	N·m
	Mounting torque(M6)					3.0	N·m
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight					320	g
Outline	214F3						

OUTLINE DRAWING & CIRCUIT DIAGRAM



